# General purpose amplification(-12V, -2A) 2SB1690

### Applications

Low frequency amplifier Deiver

### ● Features

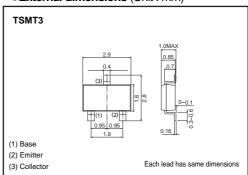
- 1) A collector current is large.
- 2) Collector saturation voltage is low.

Vce(sat): max. -180mV at Ic=-1A/IB=-50mA

# Packaging specifications

|         | Package                      | Taping |  |  |  |  |
|---------|------------------------------|--------|--|--|--|--|
| Туре    | Code                         | TL     |  |  |  |  |
|         | Basic ordering unit (pieces) | 3000   |  |  |  |  |
| 2SB1690 |                              | 0      |  |  |  |  |

### ●External dimensions (Unit : mm)



### ● Absolute maximum ratings (Ta=25°C)

| Parameter                   | Symbol | Limits      | Unit |  |
|-----------------------------|--------|-------------|------|--|
| Collector-base voltage      | Vсво   | -15         | V    |  |
| Collector-emitter voltage   | Vceo   | -12         | V    |  |
| Emitter-base voltage        | VEBO   | -6          | V    |  |
| Collector current           | lc     | -2          | Α    |  |
| Collector current           | Icp    | -4          | A *1 |  |
| Collector power dissipation | Pc     | 0.5         | W *2 |  |
| Collector power dissipation | PC     | 1           | W *3 |  |
| Junction temperature        | Tj     | 150         | °C   |  |
| Storage temperature         | Tstg   | -55 to +150 | °C   |  |

- \*1 Single pulse Pw=1ms
  \*2 Each terminal mounted on a recommended land
  \*3 Mounted on a 25mm×25mm×<sup>1</sup>0.8mm ceramic substrate

# ●Electrical characteristics (Ta=25°C)

| Parameter                             | Symbol   | Min. | Тур. | Max. | Unit | Conditions                   |
|---------------------------------------|----------|------|------|------|------|------------------------------|
| Collector-base breakdown voltage      | ВУсво    | -15  | -    | -    | ٧    | Ic=-10μA                     |
| Collector-emitter breakdown viltage   | BVceo    | -12  | -    | -    | ٧    | Ic=-1mA                      |
| Emitter-base breakdown voltage        | ВУєво    | -6   | -    | -    | ٧    | Iε=-10μA                     |
| Collector cutoff current              | Ісво     | -    | -    | -100 | nA   | Vcb=-15V                     |
| Emitter cutoff current                | ІЕВО     | _    | -    | -100 | nA   | V <sub>EB</sub> =-6V         |
| Collerctor-emitter saturation voltage | VcE(sat) | -    | -120 | -180 | mV   | Ic=-1A, Iв=-50mA             |
| DC current transfer ratio             | hfe      | 270  | -    | 680  | -    | Vce=-2V, Ic=-200mA*          |
| Transition frequency                  | f⊤       | -    | 360  | -    | MHz  | Vce=-2V, Ie=200mA, f=100MHz* |
| Output capacitance                    | Cob      | -    | 15   | -    | pF   | VcB=-10V, IE=0mA, f=1MHz     |

#### •Electrical characteristic curves

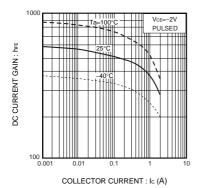


Fig.1 DC current gain vs. collector current

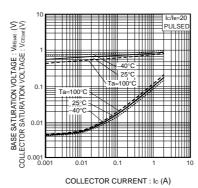


Fig.2 Collector-emitter saturation voltage base-emitter saturation voltage vs.collector current

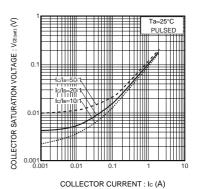


Fig.3 Collector-emitter saturation voltage vs. collector current

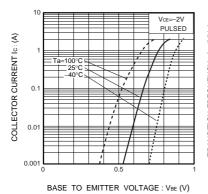


Fig.4 Grounded emitter propagation characteristics

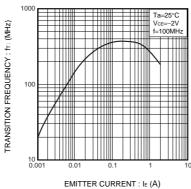


Fig.5 Gain bandwidth product vs. emitter current

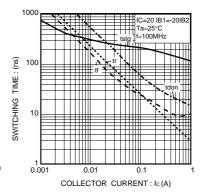


Fig.6 Switching time

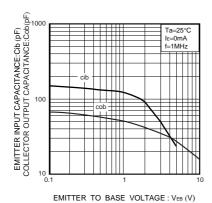


Fig.7 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

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